

2SK1968

Silicon N Channel MOS FET

Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- No secondary breakdown
- Suitable for Switching regulator
- Low drive current

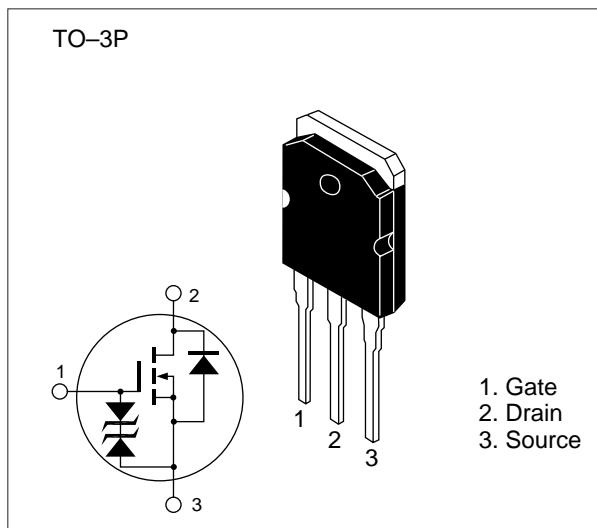


Table 1 Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	600	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	12	A
Drain peak current	I _{D(pulse)} *	48	A
Body-drain diode reverse drain current	I _{DR}	12	A
Channel dissipation	P _{ch} **	100	W
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

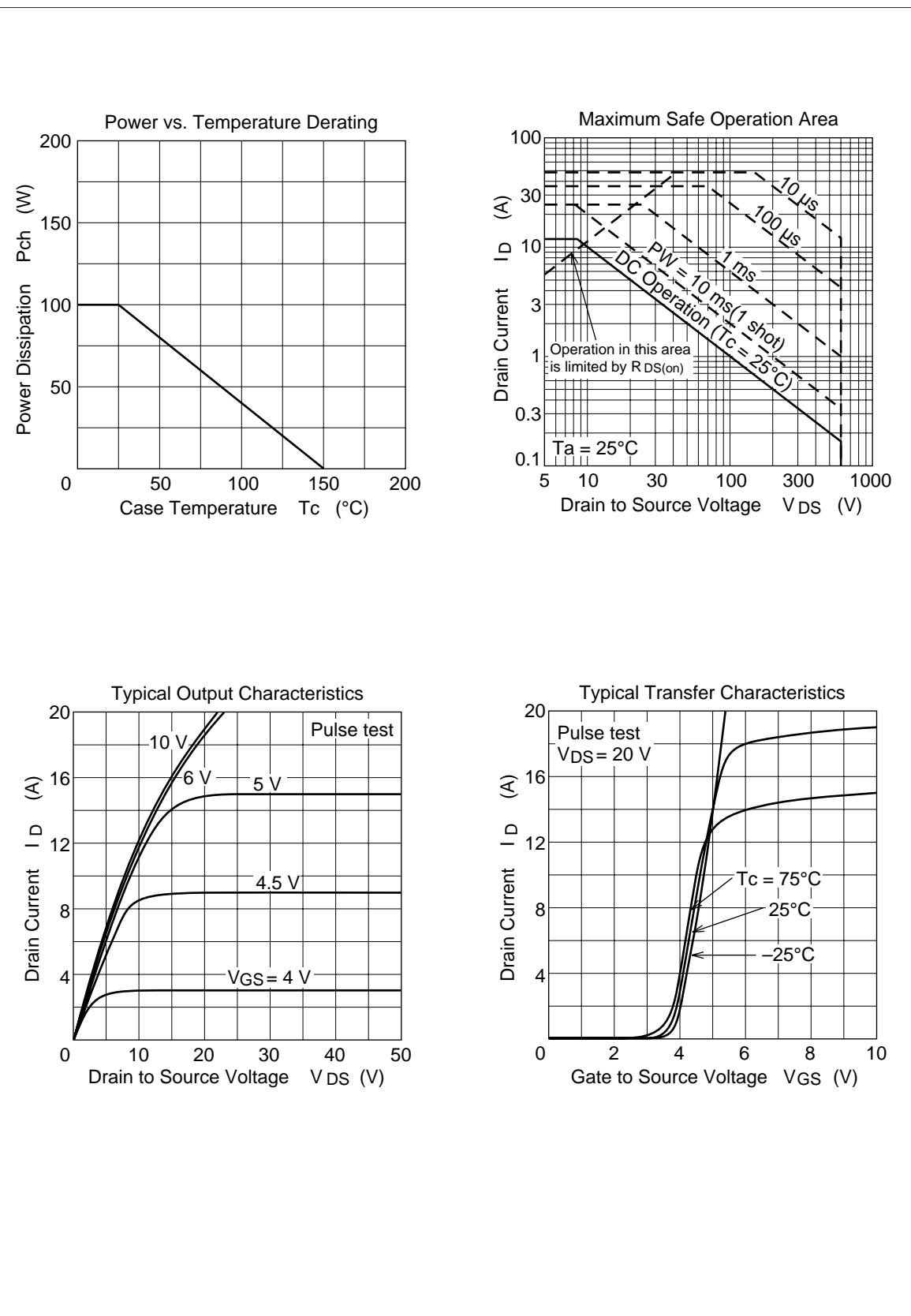
* PW ≤ 10 µs, duty cycle ≤ 1 %

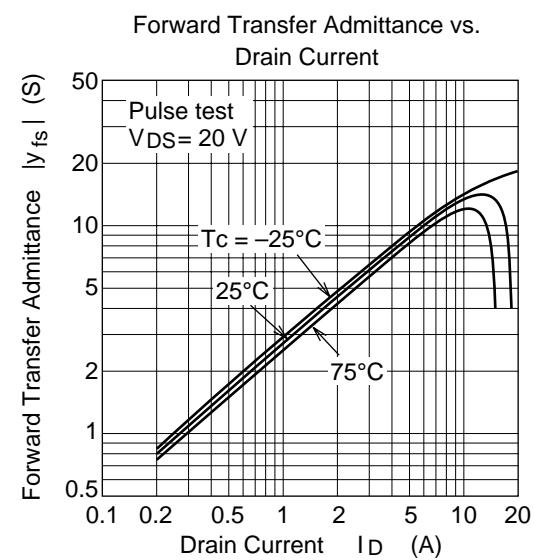
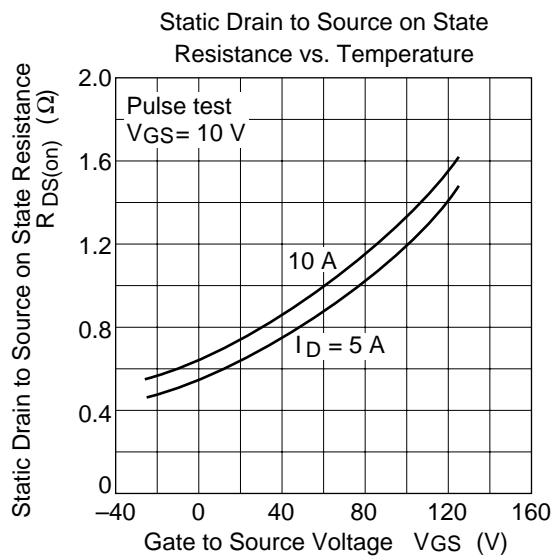
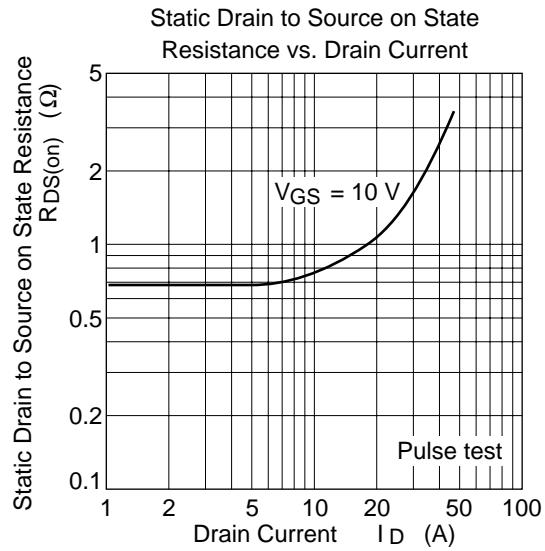
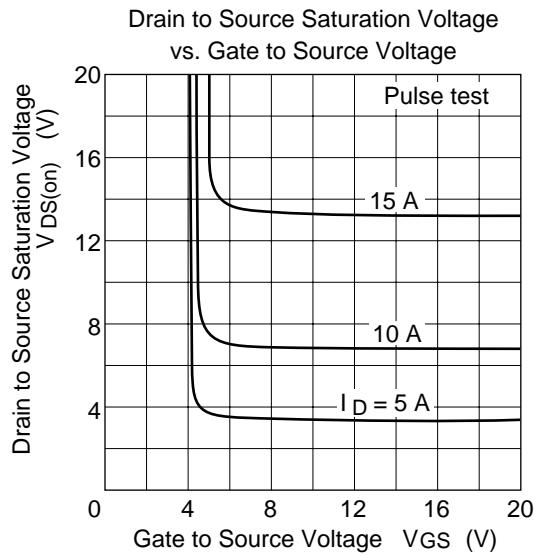
** Value at T_c = 25 °C

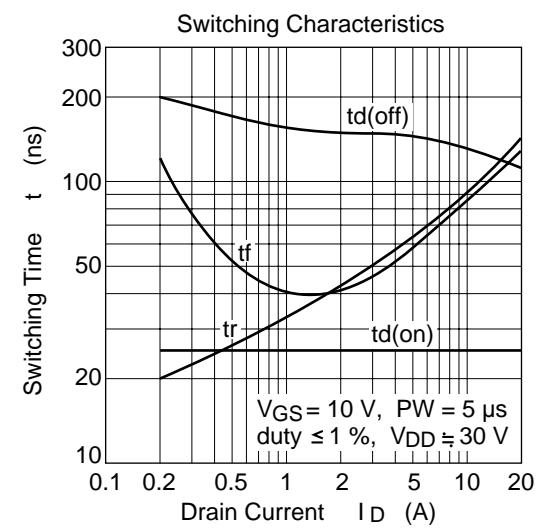
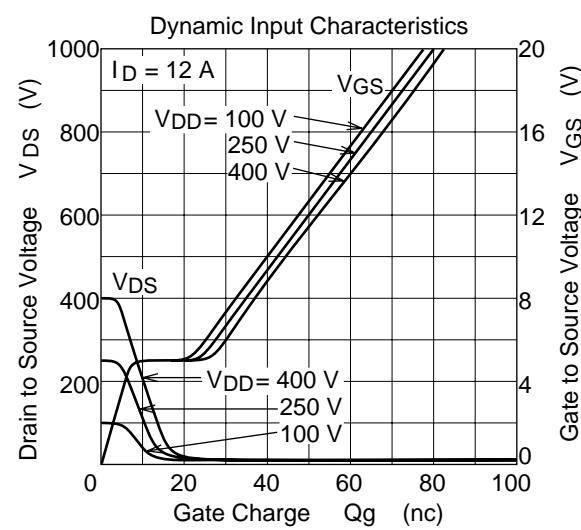
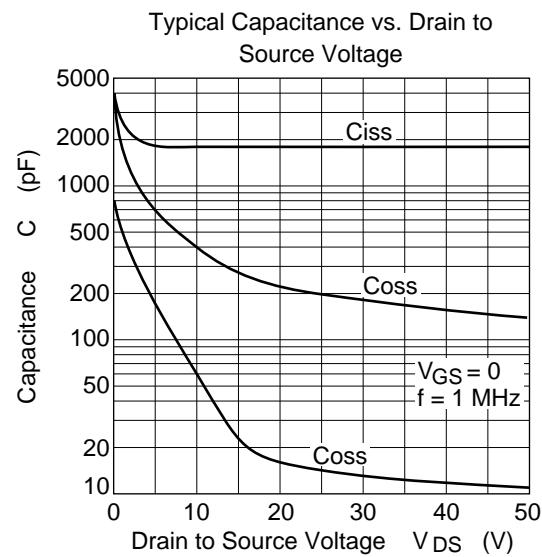
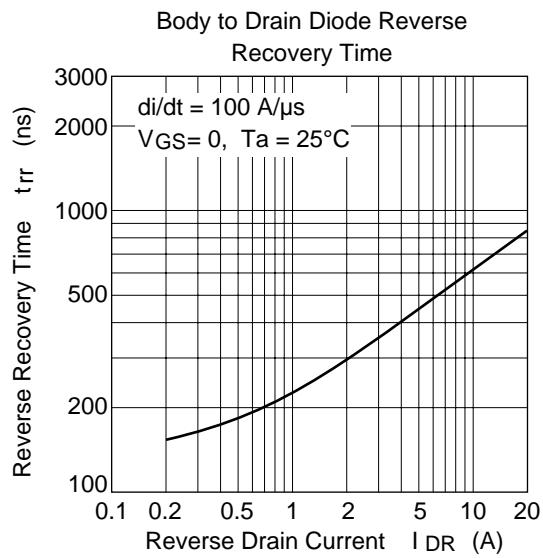
Table 2 Electrical Characteristics (Ta = 25°C)

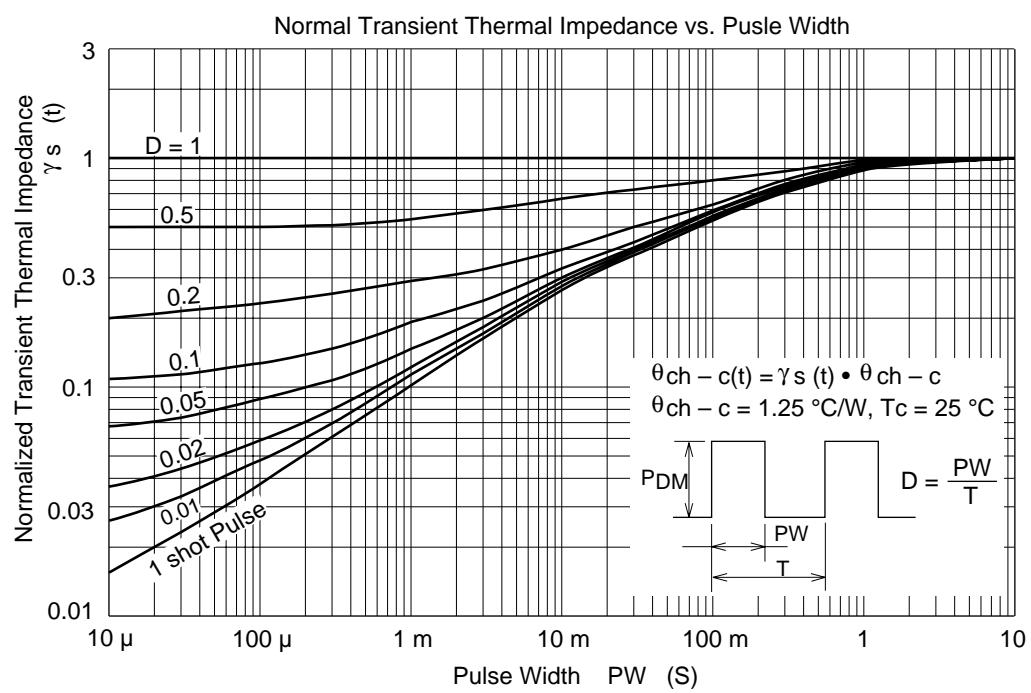
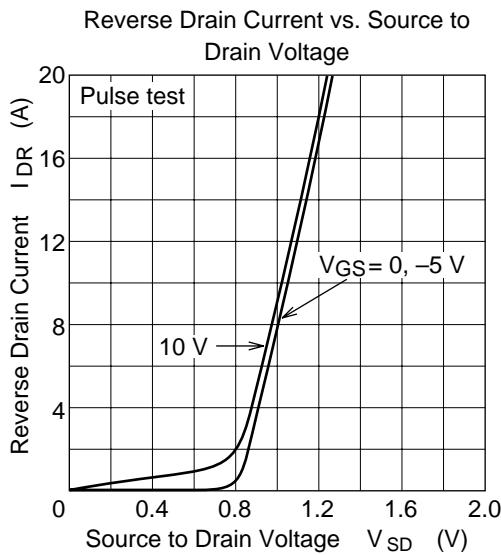
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	600	—	—	V	I _D = 10 mA, V _{GS} = 0
Gate to source breakdown voltage	V _{(BR)GSS}	±30	—	—	V	I _G = ±100 µA, V _{DS} = 0
Gate to source leak current	I _{GSS}	—	—	±10	µA	V _{GS} = ±25 V, V _{DS} = 0
Zero gate voltage drain current	I _{DSS}	—	—	250	µA	V _{DS} = 500 V, V _{GS} = 0
Gate to source cutoff voltage	V _{GS(off)}	2.0	—	3.0	V	I _D = 1 mA, V _{DS} = 10 V
Static drain to source on state resistance	R _{DS(on)}	—	0.68	0.88	Ω	I _D = 6 A V _{GS} = 10 V *
Forward transfer admittance	y _{fs}	5	10	—	S	I _D = 6 A V _{DS} = 10 V *
Input capacitance	C _{iss}	—	1800	—	pF	V _{DS} = 10 V
Output capacitance	C _{oss}	—	400	—	pF	V _{GS} = 0
Reverse transfer capacitance	C _{rss}	—	60	—	pF	f = 1 MHz
Turn-on delay time	t _{d(on)}	—	25	—	ns	I _D = 6 A
Rise time	t _r	—	70	—	ns	V _{GS} = 10 V
Turn-off delay time	t _{d(off)}	—	145	—	ns	R _L = 5 Ω
Fall time	t _f	—	65	—	ns	
Body-drain diode forward voltage	V _{DF}	—	1.1	—	V	I _F = 12 A, V _{GS} = 0
Body-drain diode reverse recovery time	t _{rr}	—	670	—	ns	I _F = 12 A, V _{GS} = 0, dI _F / dt = 100 A / µs

* Pulse Test









Switching Time Test Circuit and Waveform

